

Corporate Overview & Stack Memory Introduction

GigaDevice Semiconductor (Beijing), Inc.

May, 2018

Company Profile – Overview

- Founded in Silicon Valley, headquartered in Beijing, China.
- A fabless semiconductor company focused on advanced Non-Volatile Memory and 32-bit ARM Cortex Microcontroller solutions.
- Complete Serial Flash product portfolio including SPI NOR, SPI NAND.
- Wide range of 32-bit MCU product lines targeting various application segments.
- Strong R&D resource and capability specialized in NVM and MCU development.
- Dominating Serial Flash Memory and 32-bit MCU market in China with the largest customer base.
- First China memory supplier completed IPO at Shanghai Stock Exchange.







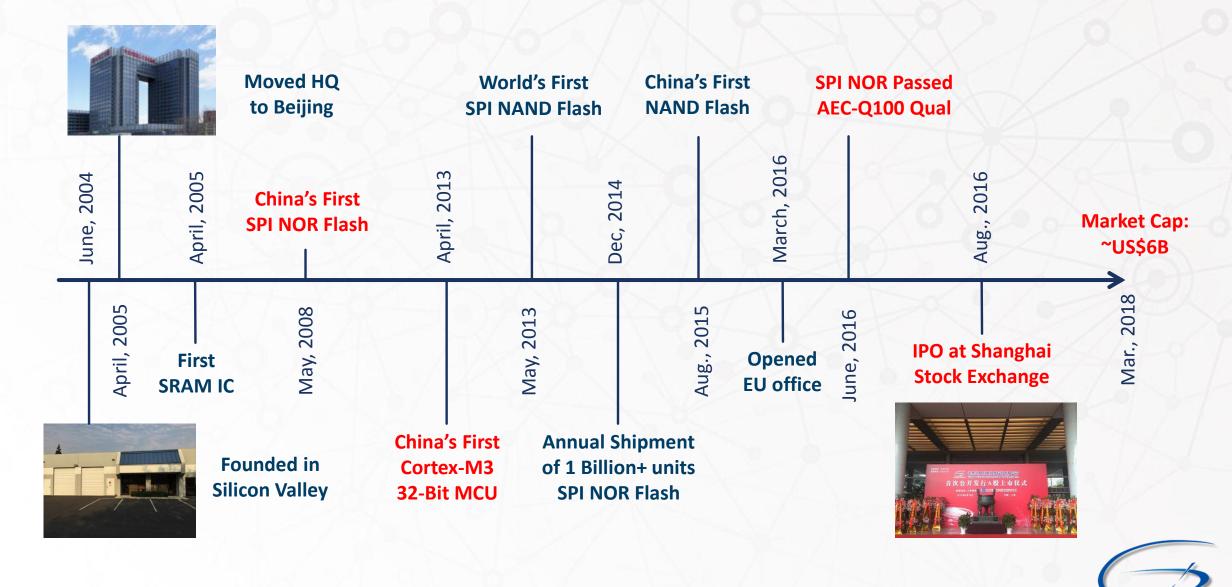


Company Profile – Numbers

2004	Year Established
3	Worldwide Ranking of Serial NOR Flash Suppliers
1	Worldwide First 8-pin Serial NAND Flash Supplier
1 & 1	China Market Share of Flash & 32-bit MCU
400+	Number of Employees
220+	Number of Patents Granted
1,700,000,000+	Annual Serial Flash Shipment Units in 2017

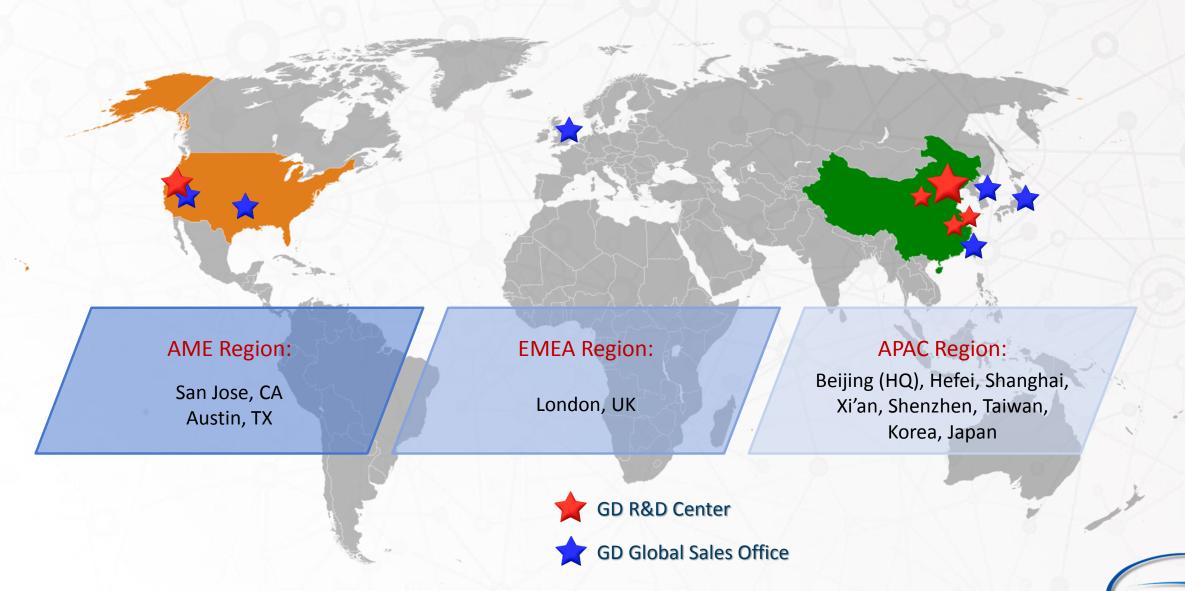


Company Profile – Milestones



GigaDevice

Company Profile – Globalization



Company Profile – Chipset Partners (for Flash)





Company Profile – Major Customers





Company Profile – Major Customers



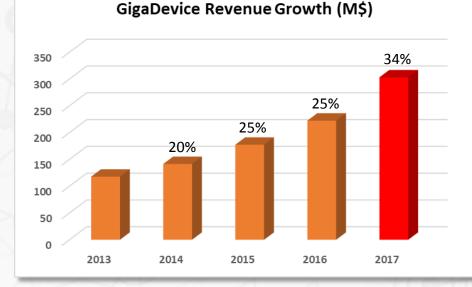


Company Profile – Growth

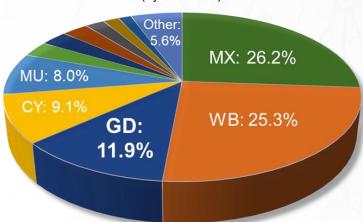
• GigaDevice has been ranked worldwide #3 Serial Flash Supplier since 2013, with ~12% market share.

• 32-bit ARM Cortex MCU shipment has grown rapidly since the introduction in 2013.

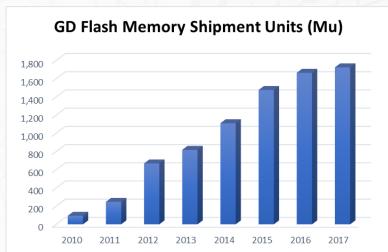
 2017 was a record-breaking year for both Flash & MCU due to global shortage.

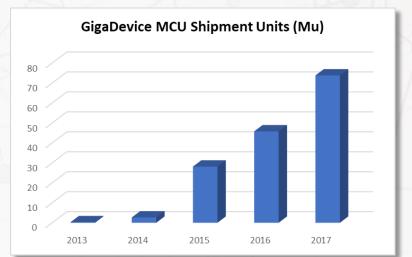






Source: Web-Feet Research, 2017







Company Profile – Manufacturing

Foundry Partners







(for MCU)

(for Flash)

Assembly Houses













Company Profile – Quality

CEO

Quality VP

Quality Org. & Function

Product Assurance

- New product Qualification
- Reliability monitor
- Customer Engineering Service
- RMA

Product Quality Control

- Supplier Control
- Non-conformity control
- Change Control
- Traceability Control
- Incoming & Outgoing Quality Assurance
- CIP

Quality System Management

- Quality Planning
- Quality System management
- Environment System Management
- Internal & External Audit
- DCC



Company Profile – Certificates



CERTIFICATE





- IONet -

This is to certify that

GigaDevice Semiconductor (Beijing) Inc.

A12, USTB Techart Plaza, Xueyuan Road 30, Haidian District 100083, Beijing P.R. China

Unified Social Credit Code: 91110108773369432Y

has implemented and maintains a Quality Management System.

Scope

Design and sales integrated circuit chip

Through an audit, documented in a report, it was verified that the management system fulfills the requirements of the following standard:

ISO 9001 : 2015

Certificate registration no. 50050943 QM15

 Valid from
 2017-09-21

 Valid until
 2020-09-20

 Date of certification
 2017-09-21



DAKKS
Deutsche
Aktreditierungsstell

DQS GmbH

Faul Gil

Frank Graichen Managing Director

Accredited Body: DQS GmbH, August-Schanz-Straße 21, 60433 Frankfurt am Main, Germany Responsible Office: DQS AP LLG, 1102-1103, Tower 2, A.R.C.H., 533 Lou-shan-guan Road, Changning District, Shanghal, 200051, China

The certificate can be verified at <u>www.dos-on.com</u> as well as CNCA official website <u>www.cnca.cov.cn</u>.

The certificate will be valid only in case that the certified organization undergoes successful periodic surveillance audit.



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ISO 14001 : 2015

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D-2M-1

DQS GmbH

Frank Graichen
Managing Director



Accredited Body: DQS GmbH, August-Schanz-Straße 21, 50433 Frankfurt am Main, Germany Responsible Office: DQS AP Ltd., 1102-1103, Tower 2, A.R.C.H., 533 Lou-shan-guan Road, Chapmany District, Shapengan 200055, Chipa



Company Profile – Awards

Years in a row!



GigaDevice received Excellent Supplier Award by Samsung for our support in 2013 / 2014 / 2015 / 2016 / 2017.



Company Profile – Product Portfolio

New Memory

- Invested in Everspin, CIYU for MRAM technology
- Joint venture with Rambus to develop RRAM

Serial NOR Flash

- World's #3 supplier
- China national standard
- Dedicated to NOR Flash market



32-bit ARM MCU

China's #1 supplier

Serial NAND Flash

- World's 1st small package supplier
- China national standard
- Defining next generation spec to lead the market

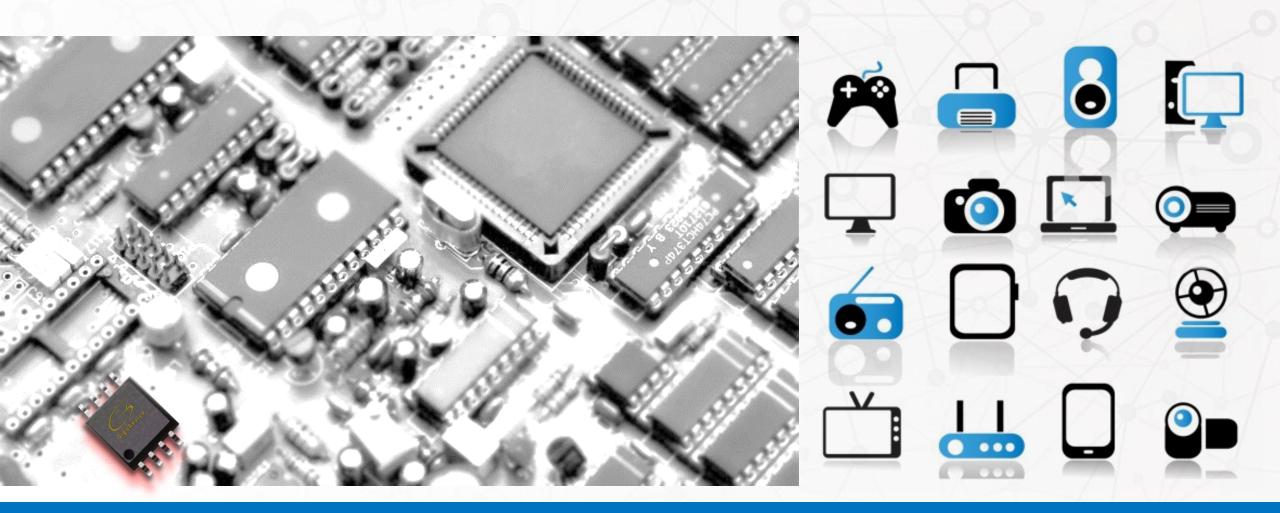


Flash Memory Introduction





Welcome to the Digital Era!



GigaDevice has powered up more than 10 Billion electronic devices since 2010!



Flash Memory Applications

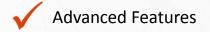
	Density	Performance	Security	Reliability	Power Consumption	Package Size
Computing	Medium ~ High	Low	Medium	Normal	Normal	Normal
Networking	High	Medium	Medium ~ High	Normal	Normal	Normal
Consumer	Low ~ High	Medium	Medium	Normal	Low ~ Normal	Normal
Mobile	Low ~ Medium	Medium	Medium	Normal	Normal	Small
Automotive	High	Very High	Medium ~ High	Very High	Normal	Normal
loT	Low ~ Medium	Low	Medium ~ High	Normal	Low	Small



Flash Memory Applications









Flash Memory Density – GD Solutions



	Density											
Computing	Medium ~ High											
Networking	High	512Kb~128Mb	256Mb	512Mb	1Gb	2Gb	4Gb	8Gb	16Gb	32Gb	64Gb	128Gb
Consumer	Low ~ High		SPI-	NOR			SPI-NAND					
Mobile	Low ~ Medium				(C	NFi-NAN	D			
Automotive	High										eMMC	
IoT	Low ~ Medium											



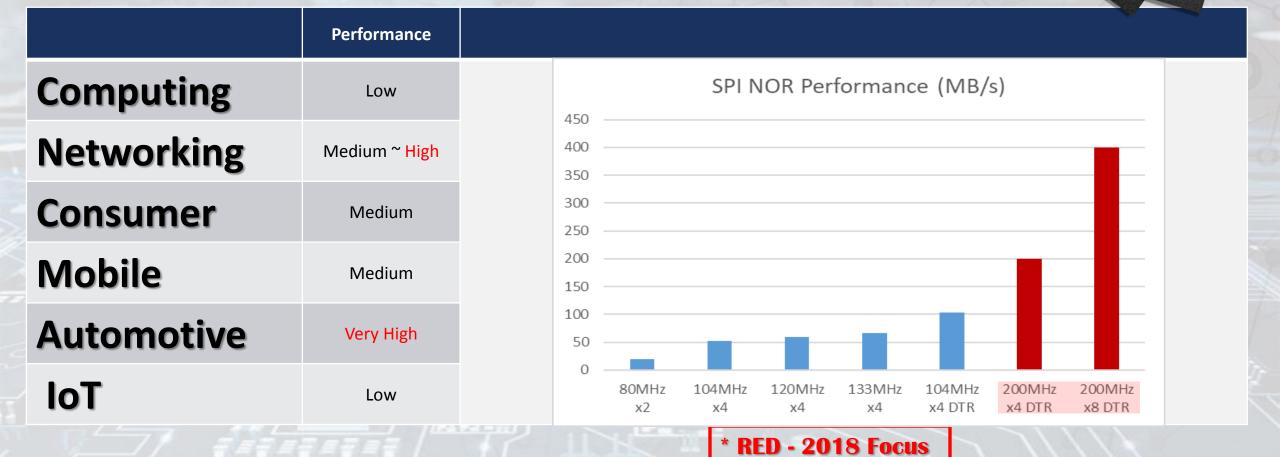
Flash Memory Density – GD Solutions



	Density	
Computing	Medium ~ High	 GigaDevice offers full density coverage for SPI NOR Flash product lines: 512Kb ~ 256Mb (512Mb / 1Gb / 2Gb in plan)
Networking	High	3V 256Mb (with ECC) is available for sample. 3V 512Mb (with "Software Die Select") is available for sample.
Consumer	Low ~ High	 NAND Flash continues the density coverage up to 64Gb: 1Gb / 2Gb / 4Gb / 8Gb, SLC technology (16Gb/32Gb/64Gb in plan)
Mobile	Low ~ Medium	SPI NAND management features improve NAND reliability. ONFi NAND to support legacy products with 2D NAND shortage.
Automotive	High	
IoT	Low ~ Medium	



Flash Memory Performance – GD Solutions





Flash Memory Performance – GD Solutions

Very High

Low

	Performance	
Computing	Low	104MHz x4 is the standard maximum Read speed for GD SPI NOR: 120 / 133MHz are supported by some new generation products.
Networking	Medium ~ High	 DTR is supported. Automotive application has driven SPI NOR Read performance to x8 I/O:
Consumer	Medium	GD joined Xccela™ Consortium with Micron, Winbond. First Octal DTR SPI product is 1.8V 256Mb with
Mobile	Medium	200MHz x8 DTR (400MB/s) data throughput.
		 However, Xccela™ SPI NOR requires new interface design by chipset:

* **RED - 2018 Focus**

Some customers may prefer current Quad SPI (x4) interface



loT

Automotive

with 200MHz DTR (200MB/s).

Flash Memory Security – GD Solutions



	Security	
Computing	Medium	All standard Security feature are support by GD SPI NOR products: Unique ID for individual device
Networking	Medium ~ High	Status Register /WP protect; Array protection OTP area for customer key storage
Consumer	Medium	 Intel developed RPMC protocol for SPI NOR Flash on PC platform: GD supports 3V RPMC with 64/128/256Mb density.
Mobile	Medium	1.8V RPMC will be available late '18.
Automotive	Medium ~ High	 GD extended RPMC feature set by adding "Memory Access Control": Typical RPMC separates memory and device authentication. GD's new concept is to put authentication in front of memory.
loT	Medium ~ High	First Product is 1.8V 16Mb with WLCSP package.



Flash Memory Reliability – GD Solutions



	Reliability						
Computing	Normal	 All GD SPI NOR products support 100K P/E Cycles and 20-yr Data Retention: 90/65/55/45nm NOR Technology 					
Networking	High	• ECC is the latest Reliability feature for GD SPI NOR products: 1-bit/8-Byte SEC/DED algorithm					
Consumer	Normal	Real-time ECC Status during Read Page Program in 8-Byte granularity First product is 3V 256Mb (GD25Q257D), in production. ECC effectively extends the product life time					
Mobile	Normal						
Automotive	Very High	 All GD SPI NAND products has on-chip ECC engine: 8-bit/512B for the current generation. 					
loT	Normal	Up to 16-bit/512B for the next generation .					



Flash Memory Power – GD Solutions



	Power Consumption						
Computing	Normal	 Typical power parameters for SPI NOR products: VCC: 3V, 1.8V 					
Networking	Normal	Deep Power Down / Standby current: 0.1 ~ 10μA Read current: 5 ~ 15mA Program/Erase current: 15 ~ 30mA					
Consumer	Low ~ Normal	• Some new features related to Low Power Consumption: Wide VCC range 1.65 ~ 3.6V "Zero" standby current: 0.1µA (no need for DPD) Active Read current: <5mA					
Mobile	Normal						
Automotive	Normal	Active Read current: <5mA Program/Erase current: <10mA					
loT	Low	 Multiple product series designed for various Low Power applications: GD25WD, GD25VE, GD25D, GD25LD, GD25LE 					



Package Highlights for SPI NOR Flash

- WLCSP (Wafer Level CSP)
 - Advantage:

package size = die size

Disadvantage:

Higher cost & difficult to handle

- Supported Products:
 - 1.8V 8Mb~128Mb







- USON8 3x2mm
 - High Yield & Low Cost
 - Smallest Molding Package
 - Supports 512Kb~16Mb
 - Introducing 1.5x1.5mm USON8

- BGA24 5x5 ball
 - Default "Octal" package defined by JEDEC
 - High Density Package



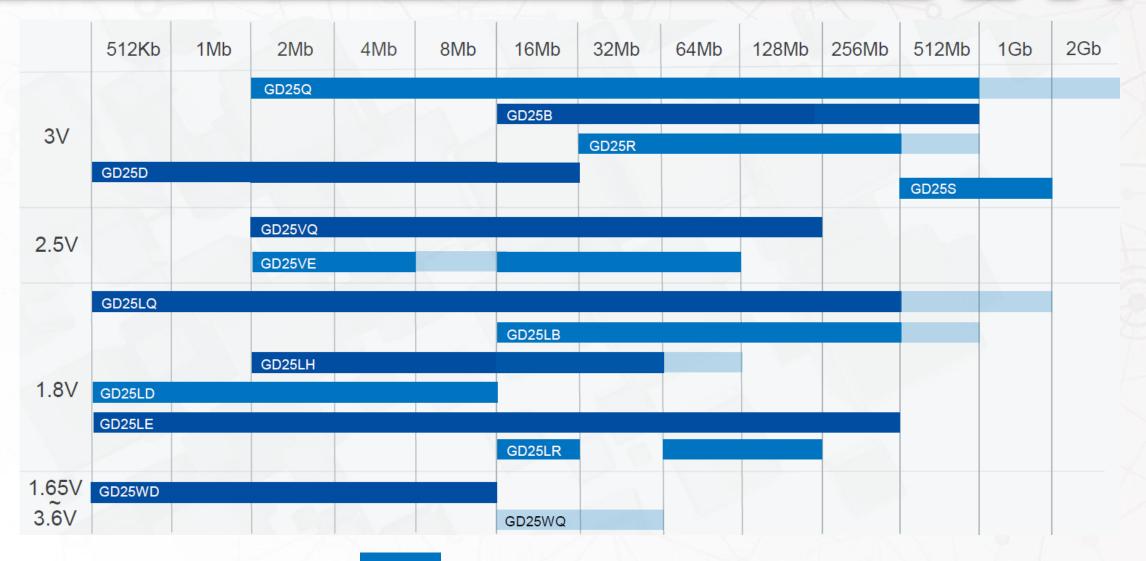
Flash Memory Package – GD Solutions

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	Package Size				
Computing	Normal	 WLCSP packages: X, Y dimensions vary from products 			
Networking	Normal	Maximum 0.5mm thickness Current devices support WLCSP: 1.8V 16/32/64/128Mb			
Consumer	Normal	 Various USON packages: USON 3x2mm, 3x3mm, 4x3mm, 3x4mm, 4x4mm, 1.5x1.5mm (new) 			
Mobile	Small	with 0.5~0.6mm thickness			
Automotive	Normal	 8x6mm TFBGA (5x5 ball array) is the key package for high density products: Support additional features (RESET#, ECC) than 8-pin packages. Future compatibility with Octal SPI Interface. 			
loT	Small	SOIC-16 may also be considered.			



SPI NOR Flash Portfolio

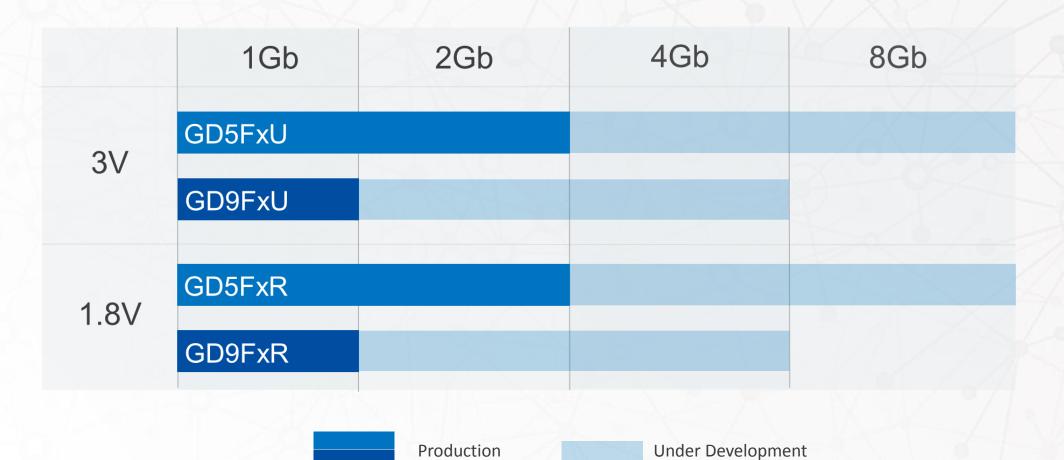




Under Development

Production

NAND Flash Portfolio (GD5F – SPI interface; GD9F – ONFi interface)





Cortex-M Microcontroller Introduction





GD32 MCU Introduction

With GigaDevice rich memory and controller IC design experiences...

- 2005 SRAM
- 2008 SPI NOR Flash
- 2013 32-bit Cortex®-M3 MCU
- 2016 32-bit Cortex®-M4 MCU





GD32 Family of 32-bit ARM® MCUs

- ✓ Latest 32-bit ARM® Cortex®-M core
- ✓ **17** complete product lines
- ✓ >300 P/Ns for selection
- ✓ Excellent performance & real-time response
- ✓ Optimized active power consumption
- ✓ Outstanding ESD & EMC level
- ✓ Rich peripherals & interface combination
- ✓ Comprehensive IDE & software compatible

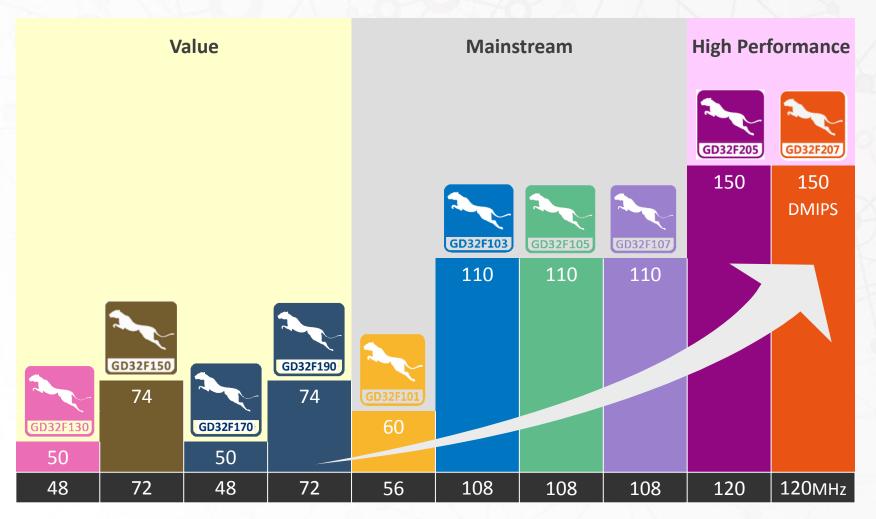




- Cost-effective
- Easy use



GD32 Cortex®-M3 Portfolio ~200 P/N



- Arm® Cortex®-M3 core
- All SMIC 110nm process
- All in mass production



GD32 Cortex®-M4 Portfolio ~100 P/N

Performance / Functionality

Cortex®-M4



Performance 200MHz Flash (KB): 512-3072

SRAM (KB): 256-512

GD32F407

Connectivity 168MHz, Ethernet MAC

Flash (KB): 512-3072 SRAM (KB): 192



Connectivity 168MHz, USB OTG HS+FS

Flash (KB): 512-3072 SRAM (KB): 192



Basic 168MHz

Flash (KB): 256-3072

SRAM (KB): 64-128



GD32F307

Mainstream 120MHz

Flash (KB): 256-3072

SRAM (KB): 48-96



Mainstream 120MHz

Flash (KB): 128-1024

SRAM (KB): 96



Mainstream 120MHz

Flash (KB): 256-1024

SRAM (KB): 96



Arm[®] Cortex[®]-M4 core

All in mass production

All UMC 55nm LP process

Value 108MHz

Flash (KB): 16-128

SRAM (KB): 4-16



Value 84MHz

Flash (KB) : 16-128

SRAM (KB): 4-16

Sept/2016

Nov/2016

Feb/2017

Mar/2017

May/2017

Year

BGA 176

BGA100

LQFP144

LQFP100

LQFP64

LQFP48

Package Type





Thank You!